

IGB01N120H2ATMA1

IGB01N120H2ATMA1 Information

www.hersener.com	 IGB01N120H2ATMA1 Infineon Technologies Discrete Semiconductor Products Transistors - IGBTs - Single IGBT 1200V 3.2A 28W TO263-3-2 TO-263-3, D2Pak (2 Leads + Tab), TO-263AB For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IGB01N120H2ATMA1 Specifications

Manufacturer Part Number	IGB01N120H2ATMA1	
Manufacturer	Infineon Technologies	
Category	Discrete Semiconductor Products	
	Transistors - IGBTs - Single	
Package	TO-263-3, D2Pak (2 Leads + Tab), TO-263AB	
Series	-	
IGBT Type	-	
Voltage - Collector Emitter Breakdown (Max)	1200V	
Current - Collector (Ic) (Max)	3.2A	
Current - Collector Pulsed (Icm)	3.5A	
Vce(on) (Max) @ Vge, Ic	2.8V @ 15V, 1A	
Power - Max	28W	
Switching Energy	140µJ	
Input Type	Standard	
Gate Charge	8.6nC	
Td (on/off) @ 25°C	13ns/370ns	
Test Condition	800V, 1A, 241 Ohm, 15V	
Reverse Recovery Time (trr)	-	
Operating Temperature	-40°C ~ 150°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	TO-263-3, D2Pak (2 Leads + Tab), TO-263AB	
Supplier Device Package	PG-TO263-3-2	
	Report errors?	

IGB01N120H2ATMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

IGB01N120H2ATMA1 Payment Methods



IGB01N120H2ATMA1 Shipping Methods



If you have any question about IGB01N120H2ATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com